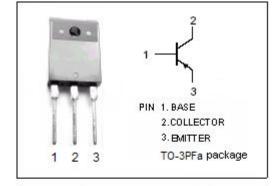


isc Silicon PNP Power Transistor

DESCRIPTION

- · Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= -140V(Min)
- · Good Linearity of hFE
- · Wide Area of Safe Operation
- Complement to Type 2SD2065
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

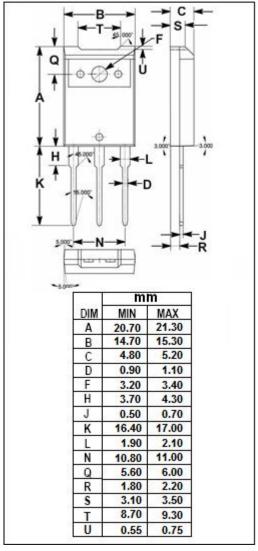


APPLICATIONS

· Designed for high power amplifications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{СВО}	Collector-Base Voltage	-140	V	
Vceo	Collector-Emitter Voltage	-140	V	
V _{EBO}	Emitter-Base Voltage	-5	V	
lc	Collector Current-Continuous	Α		
I _{CP}	Collector Current-Pulse	-12	А	
Pc	Collector Power Dissipation @ T _C =25°C	80	W	
	Collector Power Dissipation @ T _a =25 ℃	3		
TJ	Junction Temperature 150		$^{\circ}\mathbb{C}$	
T _{stg}	Storage Temperature Range -55		${\mathbb C}$	





isc Silicon PNP Power Transistor

2SB1372

ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -5A; I _B = -0.5A			-2.0	V
V _{BE(on)}	Base -Emitter On Voltage	I _C = -5A; V _{CE} = -5V			-1.8	V
I _{CBO}	Collector Cutoff Current	V _{CB} = -140V; I _E = 0			-50	μА
I _{EBO}	Emitter Cutoff Current	V _{EB} = -3V; I _C = 0			-50	μА
h _{FE-1}	DC Current Gain	I _C = -20mA; V _{CE} = -5V	20			
h _{FE-2}	DC Current Gain	I _C = -1A; V _{CE} = -5V	60		200	
h _{FE-3}	DC Current Gain	I _C = -5A; V _{CE} = -5V	20			
f _T	Current-Gain—Bandwidth Product	I _C = -0.5A; V _{CE} = -5 V; f= 1MHz		15		MHz
Сов	Output Capacitance	I _E = 0; V _{CB} = -10V; f= 1MHz		200		pF

♦ h_{FE-2}Classifications

Q	S	Р
60-120	80-160	100-200

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